



## GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

### Typical Applications

The HMC904LC5 is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications

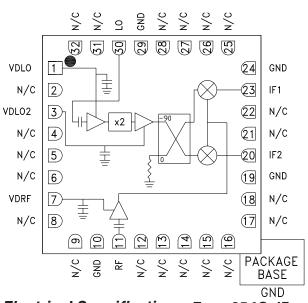
#### **Features**

Conversion Gain: 12 dB Image Rejection: 30 dB 2 LO to RF Isolation: 45 dB

Noise Figure: 3 dB Input IP3: 0 dBm

32 Lead 5x5mm SMT Package: 25mm²

### **Functional Diagram**



### **General Description**

The HMC904LC5 is a compact GaAs MMIC I/Q downconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 12 dB with a noise figure of 3 dB and 30 dB of image rejection across the frequency band. The HMC904LC5 utilizes an LNA followed by an image reject mixer which is driven by an active x2 multiplier. The image reject mixer eliminates the need for a filter following the LNA, and removes thermal noise at the image frequency. I and Q mixer outputs are provided and an external 90° hybrid is needed to select the required sideband. The HMC904LC5 is a much smaller alternative to hybrid style image reject mixer downconverter assemblies, and is compatible with surface mount manufacturing techniques.

# Electrical Specifications, $T_{\Delta} = +25 \,^{\circ}\text{C}$ , IF = 1000 MHz, LO = +4 dBm, Vdd = 3.5 Vdc USB [1]

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF	17 - 20			20 - 24		GHz	
Frequency Range, LO	7.5 - 11.75		8.25 - 12.3			GHz	
Frequency Range, IF	DC - 3.5		DC - 3.5			GHz	
Conversion Gain (As IRM)	8.5	12		8.5	12		dB
Noise Figure		3			3		dB
Image Rejection	20	35		15	30		dB
1 dB Compression (Input)		-8			-6		dBm
2 LO to RF Isolation	40	45		32	40		dB
2 LO to IF Isolation	10	15		15	20		dB
IP3 (Input)		0			0		dBm
Amplitude Balance [2]		0.25			0.25		dB
Phase Balance [2]		7			7		deg
Total Supply Current		160	190		160	190	mA

<sup>[1]</sup> Data taken as IRM with external IF 90° Hybrid

<sup>[2]</sup> Data taken without external  $90^{\circ}$  hybrid, IF = 500 MHz

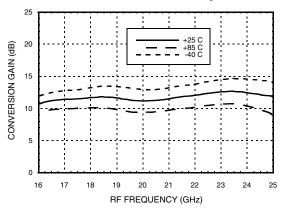




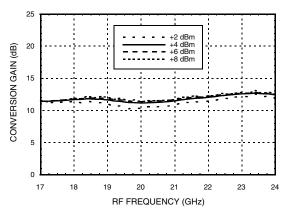
# GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

### Data Taken As IRM With External IF 90° Hybrid, IF = 1000 MHz

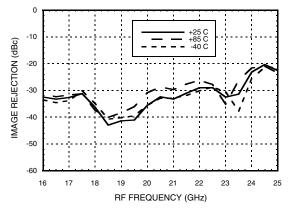
### Conversion Gain USB vs. Temperature



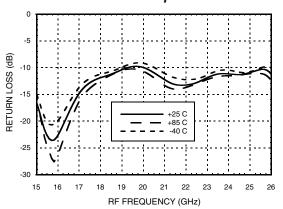
#### Conversion Gain USB vs. LO Drive



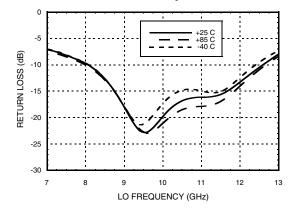
### Image Rejection vs. Temperature



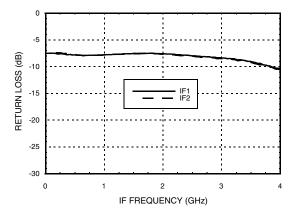
### RF Return Loss vs. Temperature



### LO Return Loss vs. Temperature



#### IF Return Loss [1]



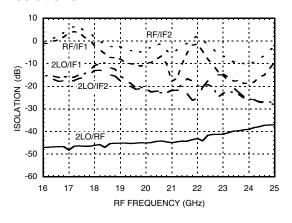
[1] Data taken without external 90° hybrid.



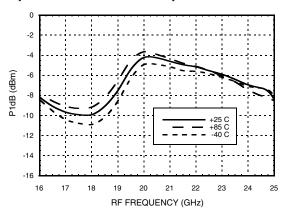


### Data Taken as IRM With External IF 90° Hybrid, IF = 1000 MHz

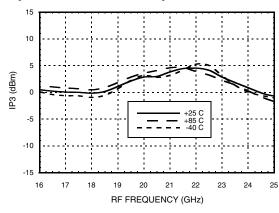
#### Isolations



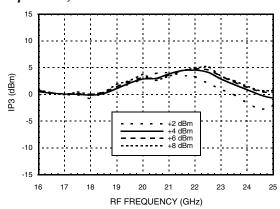
### Input P1dB USB vs. Temperature



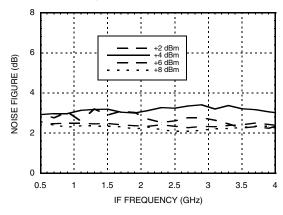
### Input IP3, USB vs. Temperature



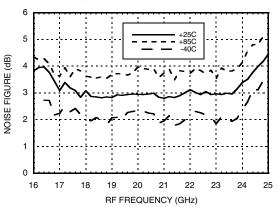
Input IP3, USB vs. LO Drive



### Noise Figure vs. LO Drive, LO Frequency = 9 GHz



Noise Figure vs. Temperature, IF Frequency = 1000 MHz



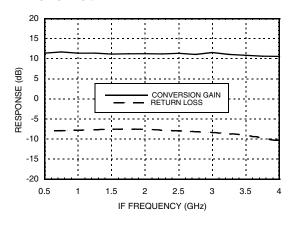
<sup>\*</sup> Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied



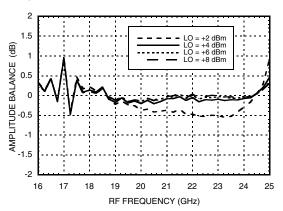


### Quadrature Channel Data Taken Without IF 90° Hybrid, IF = 1000 MHz

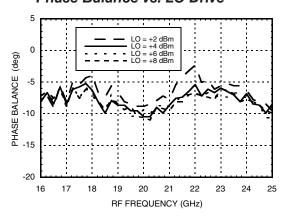
#### IF Bandwidth



### Amplitude Balance vs. LO Drive [1]



### Phase Balance vs. LO Drive [1]

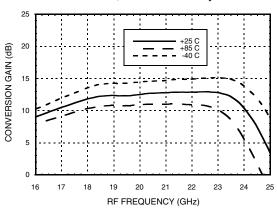




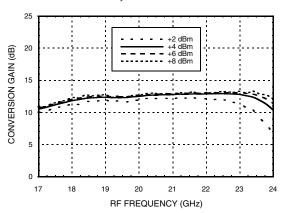


### Data Taken as IRM With External IF 90° Hybrid, IF = 1000 MHz

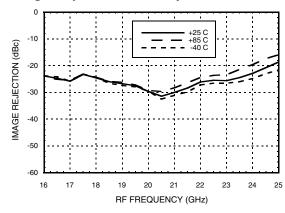
### Conversion Gain, LSB vs. Temperature



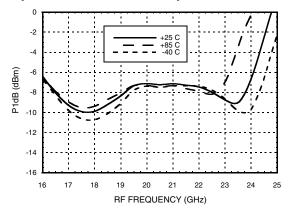
### Conversion Gain, LSB vs. LO Drive



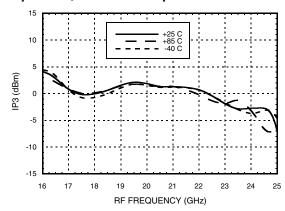
### Image Rejection vs. Temperature



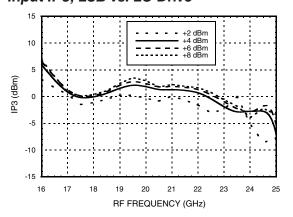
Input P1dB, LSB vs. Temperature



### Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive



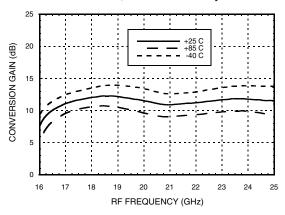
<sup>\*</sup> Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied



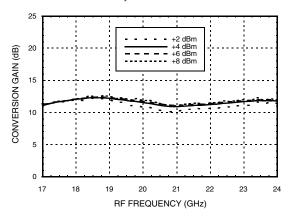


### Data Taken as IRM With External IF 90° Hybrid, IF = 2000 MHz

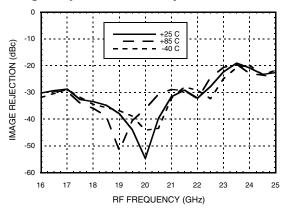
### Conversion Gain, USB vs. Temperature



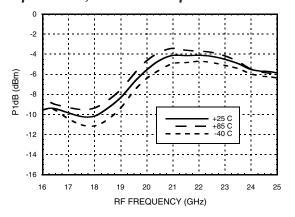
### Conversion Gain, USB vs. LO Drive



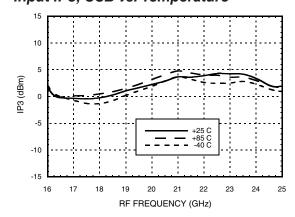
### Image Rejection vs. Temperature



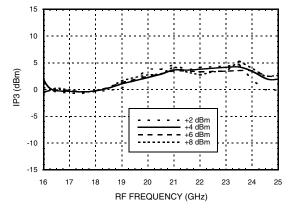
Input P1dB, USB vs. Temperature



### Input IP3, USB vs. Temperature



Input IP3, USB vs. LO Drive



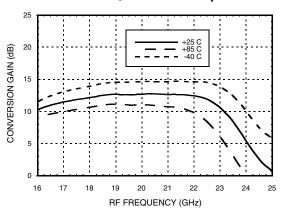
<sup>\*</sup> Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied



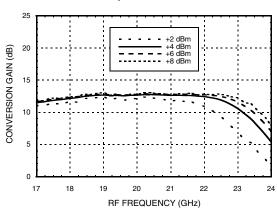


### Data Taken as IRM With External IF 90° Hybrid, IF = 2000 MHz

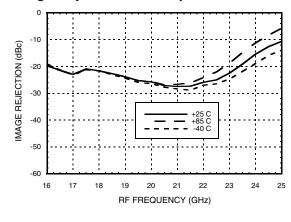
### Conversion Gain, LSB vs. Temperature



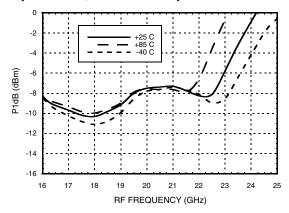
### Conversion Gain, LSB vs. LO Drive



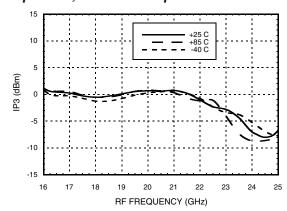
### Image Rejection vs. Temperature



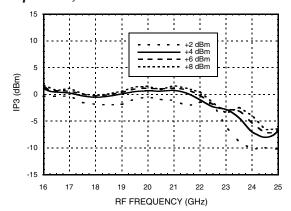
Input P1dB, LSB vs. Temperature



### Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive

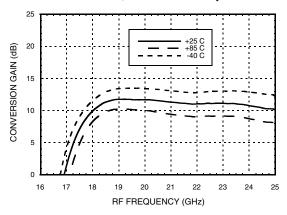




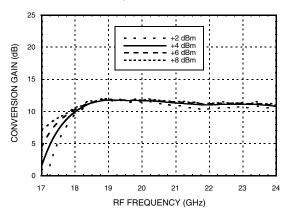


### Data Taken as IRM With External IF 90° Hybrid, IF = 3350 MHz

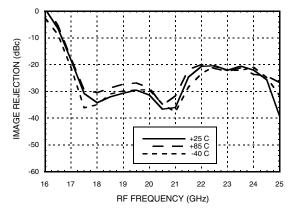
### Conversion Gain, USB vs. Temperature



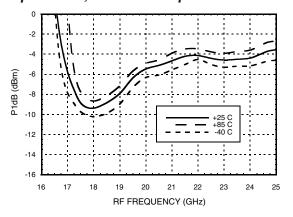
### Conversion Gain, USB vs. LO Drive



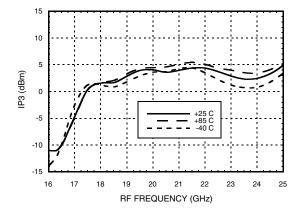
### Image Rejection vs. Temperature



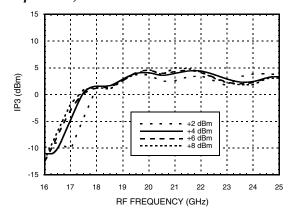
Input P1dB, USB vs. Temperature



### Input IP3, USB vs. Temperature



Input IP3, USB vs. LO Drive



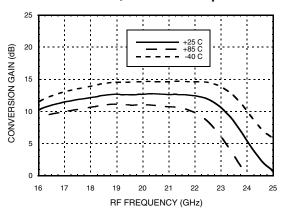
<sup>\*</sup> Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied



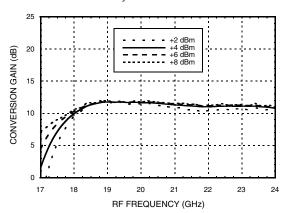


### Data Taken as IRM With External IF 90° Hybrid, IF = 3350 MHz

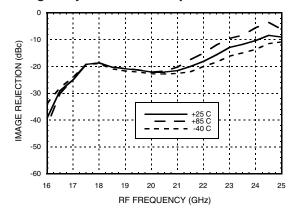
### Conversion Gain, LSB vs. Temperature



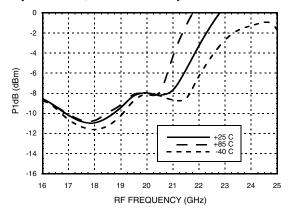
### Conversion Gain, LSB vs. LO Drive



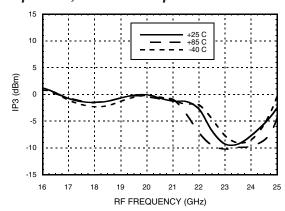
### Image Rejection vs. Temperature



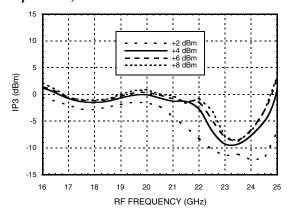
Input P1dB, LSB vs. Temperature



### Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive







# GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

### **MxN Spurious Outputs**

	1				-
	nLO				
mRF	0	1	2	3	4
0	-	17	0	23	33
1	8	26	0	23	24
2	68	95	0	66	48
3	xx	xx	xx	xx	xx
4	xx	xx	xx	xx	xx

RF = 18 GHz @ -20 dBm LO = 8.5 GHz @ +4 dBm Data taken without IF hybrid

All values in dBc below IF power level (1RF -2LO = 1 GHz)

### **Absolute Maximum Ratings**

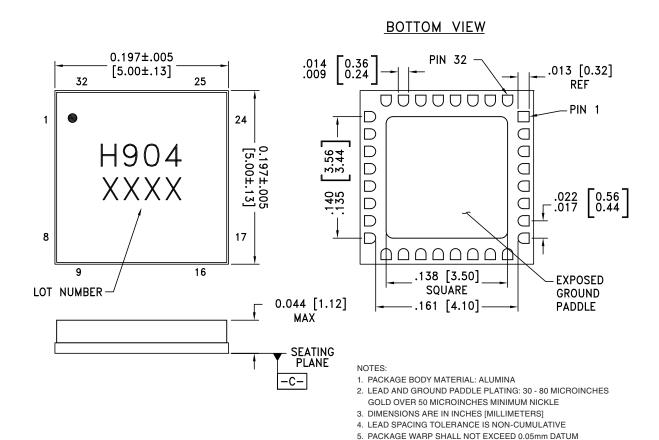
RF	+2 dBm
LO Drive	+10 dBm
Vdd	5.5V
Channel Temperature	175 °C
Continuous Pdiss (T=85°C) (derate 18.7 mW/°C above 85°C)	1.69 mW
Thermal Resistance (R <sub>TH</sub> ) (channel to package bottom)	53.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C
ESD Sensitivity (HBM)	Class 1B







### **Outline Drawing**



## **Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC904LC5	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H904 XXXX

<sup>[1]</sup> Max peak reflow temperature of 260 °C

6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED

TO PCB RF GROUND

<sup>[2] 4-</sup>Digit lot number XXXX



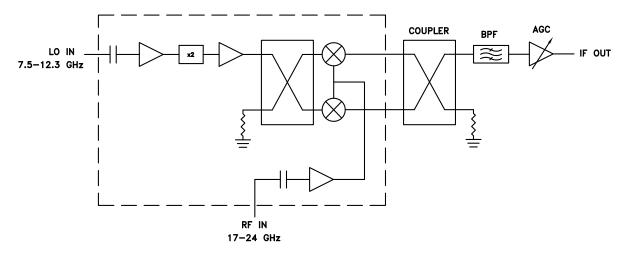


# GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	VDLO	Power supply for first stage of LO amplifier.	VDLO O
2, 4 - 6, 8, 9, 12 - 18, 21, 22, 25 - 28, 31, 32	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VDLO2	Power supply for second stage of LO amplifier.	VDLO2 ○ =
7	VDRF	Power supply for RF LNA.	
10, 19, 24, 29	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	O GND
11	RF	This pin is AC coupled and matched to 50 Ohms	RF ○—    —
20	IF2	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has	IF1,IF2 O
23	IF1	been chosen to pass the necessary frequency range.  For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	
30	LO	This pin is AC coupled and matched to 50 Ohms.	L0 ○──

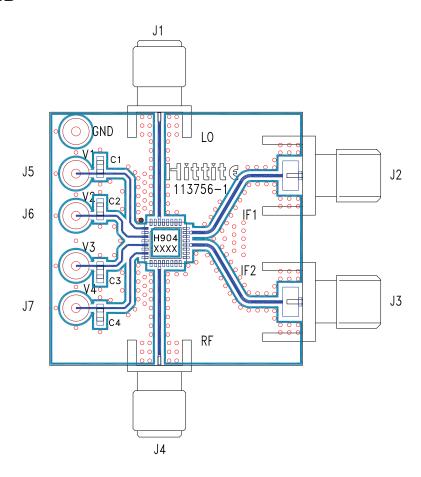
### **Typical Application Circuit**







### **Evaluation PCB**



### List of Materials for Evaluation PCB 113758 [1]

Item	Description
J1, J4	PCB Mount SMA RF Connector, SRI
J2, J3	PCB Mount SMA Connector, Johnson
J5 - J7	DC Pin
C1 - C4	0.01 μF Capacitor, 0603 Pkg.
U1	HMC904LC5
PCB [2]	113756 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.









Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

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помещение 100-Н Офис 331